

(Application Number)



(Status -- patented, pending, abandoned)

DECLARATION FOR PATENT APPLICATION

I hereby state that I have review the claims, as amended by any a I acknowledge the duty to disclose the hereby claim foreign priority be patent or inventor's certificate, a country other than the United States or inventor's certificate, and the country other than the United States or inventor's certificate, and the country other than the United States or inventor's certificate, and the country of the country of the country other than the United States or inventor's certificate, and the country of the country o	ss and citizenship are as stated and sole inventor (if only one need below) of the subject matter. ILM TRANSISTOR AND METHOD ached hereto unless the followord and understand the content amendment referred to above. The second and understand the content amendment referred to above. The second and understand the content amendment referred to above. The second and understand the content amendment referred to above. The second and understand the content amendment referred to above. The second and understand the content amendment referred to above. The second and understand the content amendment referred to above. The second and understand the content amendment referred to above. The second and understand the content amendment referred to above.	ame is listed below) or an or r which is claimed and for who and for who be a second and for who be a second and for who be a second and a second a	ecification, including in 37 CFR § 1.56. eign application(s) for ignated at least one gn application for
on which priority is claimed.			
Prior Foreign Application(s)		<u>Priority Date</u>	<u>Priority Claimed</u>
			Yes No
97-07010	KOREA	March 4, 1997	_ 🛛 🗖
(Number)	(Country) (PCT)	(Day/Month/Year Fi	led)
I hereby claim the benefit under			cation(s) listed below.
(Application Number)	(Filing D	rate)	
(Application Number)	(Filing D	(Filing Date)	
I hereby claim the benefit under International application designathe claims of this application is manner provided by the first parwhich is material to patentability the prior application and the nation	ting the United States, listed to not disclosed in the prior Unite agraph of 35 U.S.C. § 112, I as defined in 37 CFR § 1.56	pelow and, insofar as the sub d States or PCT Internationa acknowledge the duty to disc which became available bety	oject matter of each of I application in the close information
(Application Number)	(Filing Date)	Date) (Status patented, pending	

(Filing Date)

I hereby appoint the following attorney(s) and/or agent(s) to prosecute this app. business in the Patent and Trademark Office connected therewith:

Gerard F. Diebner Reg. No. 31,345 Albert L. Jacobs, Jr. Reg. No. 22,211 Israel Nissenbaum Reg. No. 27,582 Jesse D. Reingold Reg. No. 20,461 Adam B. Landa Reg. No. 35,236 Joseph R. Keating Reg. No. 37,368 Philip M. Weiss Reg. No. 34,751

Address all correspondence to:

Joseph R. Keating, Esq. Intellectual Property Group Graham & James LLP 885 Third Avenue

New York, New York 10022

(212) 848-1000

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full name of first inventor (given name, family name) Byung-Chul AHN		
Inventor's signature Bifiling Chil Ahn	Date	
Residence Kumi-shi, Kyungsangbuk-do, KOREA	Citizenship KOREA	
Post Office Address c/o LG Electronics Inc., 20 Yoido-dong, Youngdungpo-ku, Seo	ul, KOREA	
Full name of first inventor (given name, family name) Hyun-Sik SEO		
Inventor's signature Hym Sik Seo	Date Feb/18/1998	
Residence Anyang-shi, Kyungki-do, KOREA	Citizenship KOREA	
Post Office Address c/o LG Electronics Inc., 20 Yoido-dong, Youngdungpo-ku, Seo	ul, KOREA	